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FDMC8321L N-Channel Power Trench[®] MOSFET 40 V, 49 A, 2.5 m Ω

Features

- Max $r_{DS(on)}$ = 2.5 m Ω at V_{GS} = 10 V, I_D = 22 A
- Max $r_{DS(on)}$ = 4.1 m Ω at V_{GS} = 4.5 V, I_D = 18 A
- Advanced Package and Silicon combination for low r_{DS(on)} and hign efficiency
- Next Generation enhanced body diode technology, engineered for soft recovery
- 100% UIL tested
- RoHS Compliant

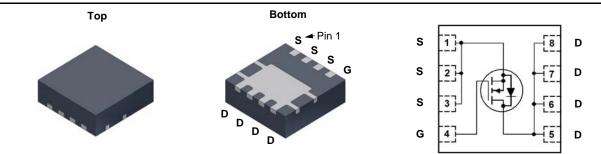


General Description

This N-Channel MOSFET has been designed specifically to improve the overall efficiency and to minimize switch node ringing of DC/DC converters using either synchronous or convertional switching PWM contollers. It has been optimized for low gate charge, low $r_{DS(on)}$, fast switching speed body diode reverse recovery performance.

Applications

- Synchronous rectifier
- Load switch/Orring
- Motor switch



Power 33

MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

| Symbol | Parameter | | | Ratings | Units | | | |
|-----------------------------------|--|-------------------|------------------------|-----------|-------------|----|--|--|
| V _{DS} | Drain to Source Voltage | | | 40 | V | | | |
| V _{GS} | Gate to Source V | /oltage | | | ±20 | V | | |
| | Drain Current | -Continuous | T _C = 25 °C | | 49 | | | |
| I _D | | -Continuous | T _A = 25 °C | (Note 1a) | 22 | А | | |
| | | -Pulsed | | | 100 | | | |
| E _{AS} | Single Pulse Ava | lanche Energy | | (Note 3) | 86 | mJ | | |
| P _D | Power Dissipatio | n | T _C = 25 °C | | 40 | w | | |
| | Power Dissipation | Power Dissipation | | (Note 1a) | 2.3 | vv | | |
| T _J , T _{STG} | Operating and Storage Junction Temperature Range | | | | -55 to +150 | °C | | |

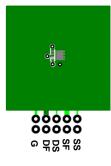
Thermal Characteristics

| $R_{	ext{	heta}JC}$ | Thermal Resistance, Junction to Case | (Note 1) | 3.1 | °C/W | |
|---------------------|---|-----------|-----|------|--|
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | (Note 1a) | 53 | C/VV | |

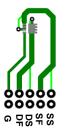
Package Marking and Ordering Information

| Device Marking | Device | Package | Reel Size | Tape Width | Quantity |
|----------------|-----------|---------|-----------|------------|------------|
| FDMC8321L | FDMC8321L | Power33 | 13 " | 12 mm | 3000 units |

| | al Characteristics $T_J = 25 \text{ °C}$ unle | | | | | |
|--|---|---|---------|------|------|-------|
| Symbol | Parameter | Test Conditions | Min | Тур | Max | Units |
| Off Chara | acteristics | | | | | |
| BV _{DSS} | Drain to Source Breakdown Voltage | I _D = 250 μA, V _{GS} = 0 V | 40 | | | V |
| ΔBV _{DSS} ΔTJ | Breakdown Voltage Temperature Coefficient | $I_D = 250 \ \mu\text{A}$, referenced to 25 °C | | 22 | | mV/°C |
| I _{DSS} | Zero Gate Voltage Drain Current | $V_{DS} = 32 \text{ V}, V_{GS} = 0 \text{ V}$ | | | 1 | μA |
| I _{GSS} | Gate to Source Leakage Current | $V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$ | | | ±100 | nA |
| On Chara | octeristics | | | | | |
| V _{GS(th)} | Gate to Source Threshold Voltage | $V_{GS} = V_{DS}, \ I_{D} = 250 \ \mu A$ | 1 | 1.7 | 3 | V |
| $\frac{\Delta V_{GS(th)}}{\Delta T_J}$ | Gate to Source Threshold Voltage Temperature Coefficient | $I_D = 250 \ \mu$ A, referenced to 25 °C | | -5 | | mV/°C |
| r _{DS(on)} | Static Drain to Source On Resistance | V _{GS} = 10 V, I _D = 22 A | 1.9 2.5 | | | |
| | | V _{GS} = 4.5 V, I _D = 18 A | | 2.7 | 4.1 | mΩ |
| | | V_{GS} = 10 V, I _D = 22 A, T _J = 125 °C | | 2.8 | 3.7 | |
| 9 _{FS} | Forward Transconductance | $V_{DS} = 5 V, I_{D} = 22 A$ | | 114 | | S |
| - | Characteristics | | | T | 1 | |
| C _{iss} | Input Capacitance | V _{DS} = 20 V, V _{GS} = 0 V, | | 2930 | 3900 | pF |
| C _{oss} | Output Capacitance | -f = 1 MHz | | 1000 | 1330 | pF |
| C _{rss} | Reverse Transfer Capacitance | | | 60 | 90 | pF |
| R _g | Gate Resistance | | 0.1 | 0.7 | 2.5 | Ω |
| Switching | g Characteristics | | | | | |
| t _{d(on)} | Turn-On Delay Time | | | 12 | 22 | ns |
| t _r | Rise Time | V _{DD} = 20 V, I _D = 22 A, | | 6.1 | 12 | ns |
| t _{d(off)} | Turn-Off Delay Time | V_{GS} = 10 V, R_{GEN} = 6 Ω | | 32 | 51 | ns |
| t _f | Fall Time | | | 4.9 | 10 | ns |
| Q _{g(TOT)} | Total Gate Charge at 10 V | | | 44 | 61 | nC |
| Q _{g(TOT)} | Total Gate Charge at 5 V | – V _{DD} = 20 V, I _D = 22 A | | 21 | 32 | nC |
| Q _{gs} | Total Gate Charge | VDD - 20 V, ID - 22 A | | 7.7 | | nC |
| Q _{gd} | Gate to Drain "Miller" Charge | | | 5.8 | | nC |
| Drain-Sou | urce Diode Characteristics | | | | | |
| N/ | Source to Drain Diade, Forward Valtage | $V_{GS} = 0 V, I_S = 2 A$ (Note 2) | | 0.69 | 1.2 | V |
| V _{SD} | Source to Drain Diode Forward Voltage | $V_{GS} = 0 V, I_S = 22 A$ (Note 2) | | 0.77 | 1.3 | v |
| t _{rr} | Reverse Recovery Time | I _F = 22 A, di/dt = 100 A/μs | | 41 | 65 | ns |
| Q _{rr} | Reverse Recovery Charge | F = 22 A, ui/ul = 100 A/µS | | 20 | 33 | nC |



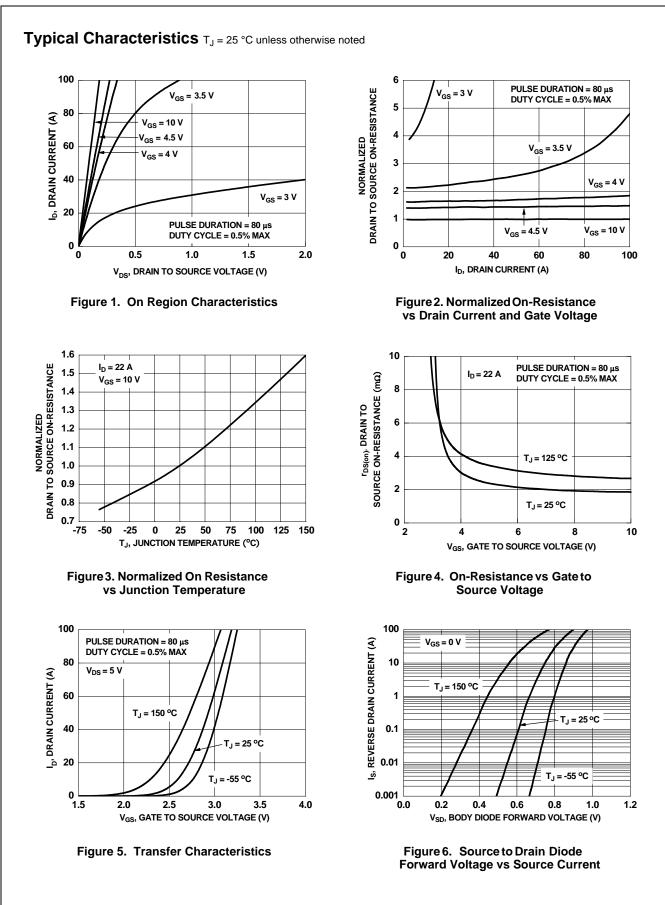
53 °C/W when mounted on a 1 in² pad of 2 oz copper



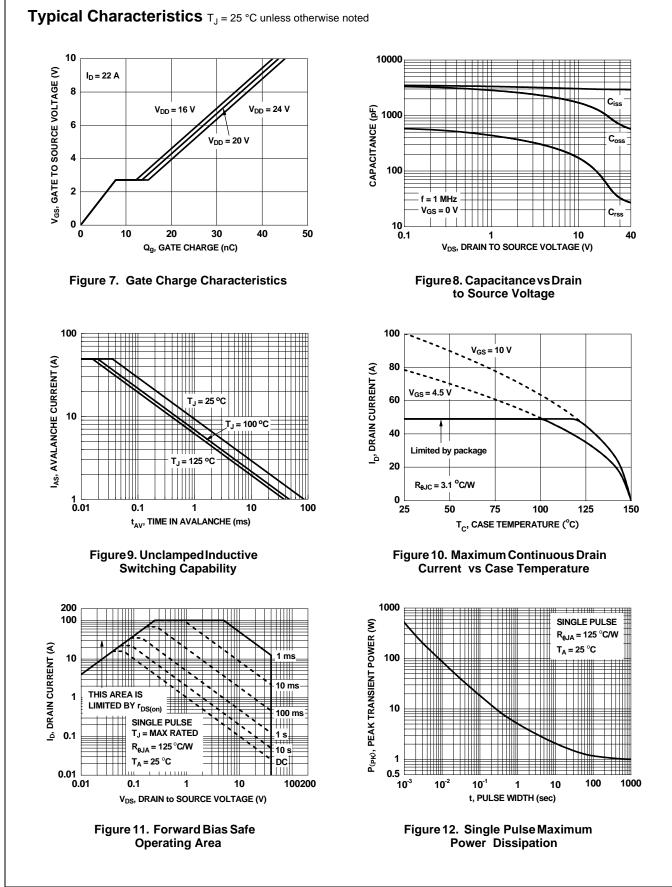
125 °C/W when mounted on a minimum pad of 2 oz copper

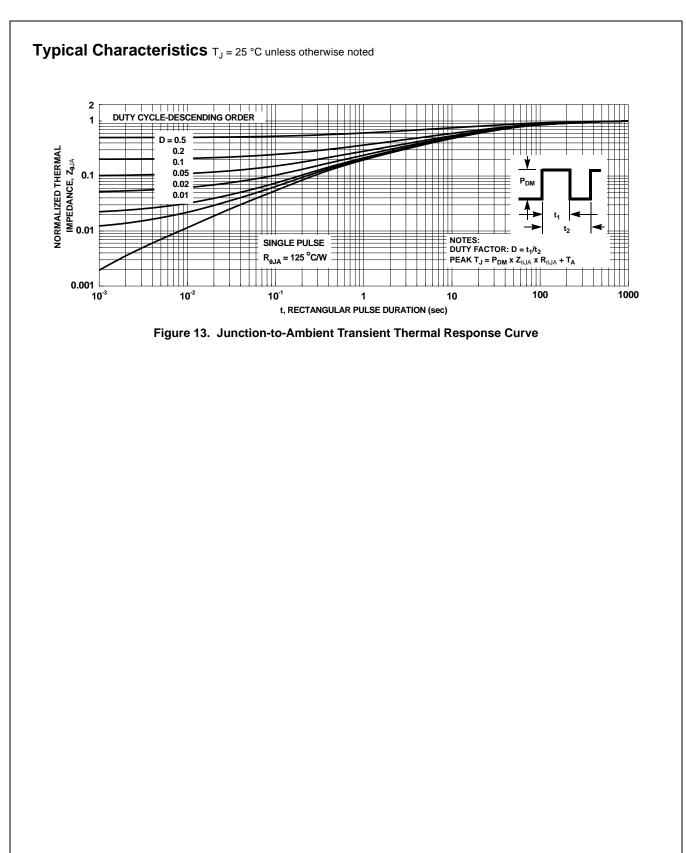
2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0%.

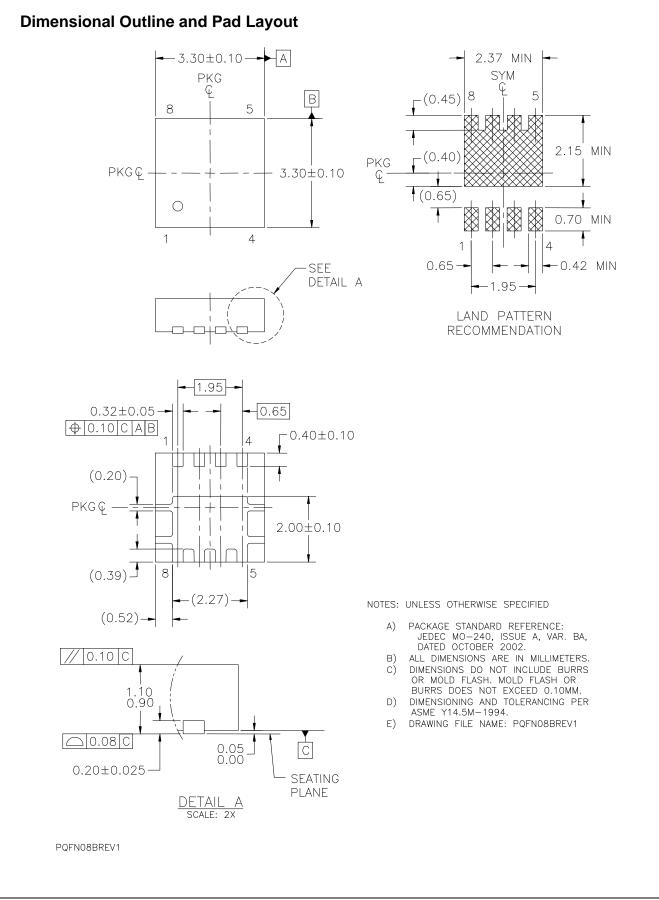
3.Starting T_J = 25 °C; N-ch: L = 0.3 mH, I_{AS} = 24 \text{ A}, V_{DD} = 36 V, V_{GS} = 10 V.











FDMC8321L N-Channel PowerTrench[®] MOSFET



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FDMC8321L N-Channel PowerTrench[®] MOSFE⁻

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